- State-of-the-Art *EPIC*-II*B*[™] BiCMOS Design Significantly Reduces Power Dissipation
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Latch-Up Performance Exceeds 500 mA Per JESD 17
- Typical V_{OLP} (Output Ground Bounce) < 1 V at V_{CC} = 5 V, T_A = 25°C
- High-Drive Outputs (-32-mA I_{OH}, 64-mA I_{OL})
- Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), and Thin Shrink Small-Outline (PW) Packages, Ceramic Chip Carriers (FK), and Plastic (N) and Ceramic (J) DIPs

description

These octal bus transceivers provide for asynchronous communication between data buses. The control-function implementation allows for maximum flexibility in timing. The 'ABT620 devices provide inverted data at the outputs.

These devices allow data transmission from the A bus to the B bus or from the B bus to the A bus, depending on the logic levels at the output-enable (OEAB and OEBA) inputs.

The output-enable inputs can be used to disable the device so that the buses are effectively isolated. The dual-enable configuration gives the transceivers the capability of storing data by simultaneously enabling OEAB and OEBA. When both OEAB and OEBA are enabled and all other data sources to the two sets of bus lines are at high impedance, both sets of bus lines (16 total) remain at their last states. In this way, each output reinforces its input in this configuration.

To ensure the high-impedance state during power up or power down, \overline{OEBA} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver. OEAB should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

The SN54ABT620 is characterized for operation over the full military temperature range of -55° C to 125° C. The SN74ABT620 is characterized for operation from -40° C to 85° C.



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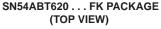
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SN74ABT620DB, DW, N, OR PW PACKAGE (TOP VIEW)						
OEAB [1 A1 [2 A2 [3 A3 [4 A4 [5 A5 [6 A6 [7 A7 [8 A8 [9 GND [10	20 V _{CC} 19 OEBA 18 B1 17 B2 16 B3 15 B4 14 B5 13 B6 12 B7 11 B8					
	F					

SN54ABT620 . . . J PACKAGE



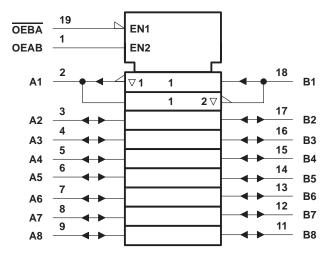
	A2 A1 OEAB VCC <u>OEBA</u>
A3	3 2 1 20 19 4 18 B1
A4	5 17 B2
A3 A4 A5 A6 A7	6 16 B3
A6	7 15 B4
A7	8 14 B5
	9 10 11 12 13
	A8 GND B8 B7 B6 B6
	U

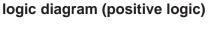
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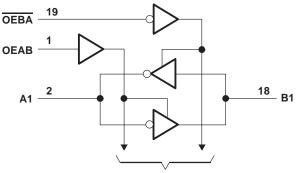
FUNCTION TABLE

INP	UTS	OPERATION						
OEBA	OEAB	OPERATION						
L	L	B data to A bus						
L	н	B data to A bus, A data to B bus						
н	L	Isolation						
Н	Н	A data to B bus						

logic symbol[†]







To Seven Other Channels

[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[‡]

Supply voltage range, V _{CC}	
Input voltage range, V _I (see Note 1)	–0.5 V to 7 V
Voltage range applied to any output in the high or power-off s	tate, V _O
Current into any output in the low state, IO: SN54ABT620 .	
	128 mA
Input clamp current, I _{IK} (V _I < 0)	
Output clamp current, I_{OK} (V _O < 0)	
Package thermal impedance, θ_{JA} (see Note 2): DB package	115°C/W
DW package	
PW package	128°C/W
Storage temperature range, T _{stg}	

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.



recommended operating conditions (see Note 3)

			SN54A	BT620	SN74A	BT620	UNIT
			MIN	MAX	MIN	MAX	UNIT
Vcc	Supply voltage		4.5	5.5	4.5	5.5	V
VIH	High-level input voltage		2	EW	2		V
VIL	Low-level input voltage			0.8		0.8	V
VI	Input voltage		0 <	Vcc	0	VCC	V
ЮН	High-level output current		ý,	-24		-32	mA
IOL	Low-level output current		202	48		64	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	Outputs enabled	A.	5		5	ns/V
ТА	Operating free-air temperature		-55	125	-40	85	°C

NOTE 3: All unused pins (control or I/O) of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CON		т	A = 25°C	;	SN54A	BT620	SN74ABT620		
		TEST CONDITIONS			TYP†	MAX	MIN	MAX	MIN	MAX	UNIT
VIK		V _{CC} = 4.5 V,	lj = -18 mA			-1.2		-1.2		-1.2	V
		V _{CC} = 4.5 V,	I _{OH} = -3 mA	2.5			2.5		2.5		
Vari		V _{CC} = 5 V,	I _{OH} = -3 mA	3			3		3		V
VOH		V _{CC} = 4.5 V	I _{OH} = -24 mA	2			2				v
		VCC = 4.3 V	I _{OH} = -32 mA	2*					2		
VOL		V _{CC} = 4.5 V	I _{OL} = 48 mA			0.55		0.55			V
VOL		VCC = 4.3 V	I _{OL} = 64 mA			0.55*				0.55	v
V _{hys}					100						mV
ŧ	Control inputs	V _{CC} = 5.5 V,	VI = VCC or GND			±1		±1		±1	μA
	A or B ports	VCC = 3.3 V,				±100		±100		±100	μΛ
IOZH‡		V _{CC} = 5.5 V,	V _O = 2.7 V			50		50		50	μΑ
I_{OZL}^{\ddagger} $V_{CC} = 5.5$ V		V _{CC} = 5.5 V,	$V_{O} = 0.5 V$			-50		50		-50	μΑ
I _{off} V _{CC}		V _{CC} = 0,	VI or VO ≤ 4.5 V			±100	~	ζ		±100	μΑ
ICEX		V _{CC} = 5.5 V, V _O = 5.5 V	Outputs high			50	0000	50		50	μA
ΙΟ§		V _{CC} = 5.5 V,	V _O = 2.5 V	-50	-100	-180	2 –50	-180	-50	-180	mA
		V _{CC} = 5.5 V,	Outputs high		5	250		250		250	μΑ
ICC	A or B ports	$I_{O} = 0,$	Outputs low		24	30		30		30	mA
		$V_I = V_{CC}$ or GND	Outputs disabled		0.5	250		250		250	μΑ
	Doto inputo	V _{CC} = 5.5 V, One input at 3.4 V,	Outputs enabled			1.5		1.5		1.5	
		Data inputs Other inputs at V _{CC} or GND				0.05		0.05		0.05	mA
	Control inputs	$V_{CC} = 5.5 V$, One inp Other inputs at V_{CC} of				1.5		1.5		1.5	
Ci	Control inputs	VI = 2.5 V or 0.5 V			4						pF
Cio	A or B ports	V _O = 2.5 V or 0.5 V			7						pF

* On products compliant to MIL-PRF-38535, this parameter does not apply.

[†] All typical values are at $V_{CC} = 5 V$.

[‡] The parameters I_{OZH} and I_{OZL} include the input leakage current.

§ Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

 \P This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

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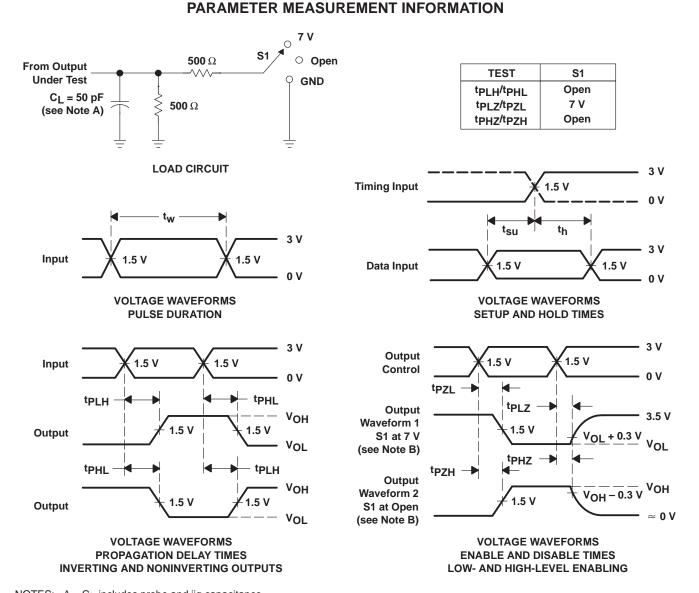
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switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM TO (INPUT) (OUTPUT)		V _{CC} =	V _{CC} = 5 V, T _A = 25°C		SN54ABT620		SN74ABT620	
	(INFOT)	(001F01)	MIN	MAX	MIN	MAX	MIN	MAX	
^t PLH	A or B	B or A	1	4.1	1		1	4.8	ns
^t PHL	AOLP	BOIA	1	4.3	1	2	1	4.8	115
^t PZH	OEBA	А	1.3	4.6	1.3	NE	1.3	5.5	ns
^t PZL	OEBA	~	1	6.1	1	3E	1	7.1	115
^t PHZ	OEBA	А	2	6.3	2	2	2	7	ns
^t PLZ	OEBA	~	1.4	5.4	1.4		1.4	5.8	115
^t PZH	OEAB	В	1.6	6.2	d .6		1.6	6.8	ns
^t PZL	UEAB	D	2	5.9	č 2		2	6.4	115
^t PHZ	OEAB	В	1.2	5.6	1.2		1.2	6.5	ns
^t PLZ	UEAB	0	1.1	4.7	1.1		1.1	5.6	115



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NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_f \leq 2.5 ns, t_f \leq 2.5 ns.

D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms





11-Apr-2013

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
SN74ABT620DBLE	OBSOLETE	SSOP	DB	20		TBD	Call TI	Call TI	-40 to 85		
SN74ABT620DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABT620	Samples
SN74ABT620DWE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABT620	Samples
SN74ABT620DWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABT620	Samples
SN74ABT620DWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABT620	Samples
SN74ABT620DWRE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABT620	Samples
SN74ABT620DWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABT620	Samples
SN74ABT620N	ACTIVE	PDIP	Ν	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	SN74ABT620N	Samples
SN74ABT620NE4	ACTIVE	PDIP	Ν	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	SN74ABT620N	Samples
SN74ABT620NSR	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABT620	Samples
SN74ABT620NSRE4	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABT620	Samples
SN74ABT620NSRG4	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABT620	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.



PACKAGE OPTION ADDENDUM

11-Apr-2013

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above. Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74ABT620DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
SN74ABT620NSR	SO	NS	20	2000	330.0	24.4	8.2	13.0	2.5	12.0	24.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

26-Jan-2013



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74ABT620DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74ABT620NSR	SO	NS	20	2000	367.0	367.0	45.0

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